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REMARKS

SEP 13 2006

Claims 14-20, 22-29, and 32-34 are pending in the present application. Claims 1-13, 21 and 30-31 were previously cancelled. Claims 20, 24, and 32 have been amended herein. No new matter has been added. Applicants respectfully request reconsideration of the claims in view of the following remarks.

Applicants would like to thank the Examiner for allowing claims 14-19, 22-29, and 32-34.

Claim 20 has been rejected under 35 U.S.C. § 102(e) as assertedly being anticipated by Cabral et al. (U.S. Patent Publication No. 2004/0092073 A1, hereinafter "Cabral"). Applicants respectfully traverse this rejection.

Claim 20 has been amended to recite "the capacitor is formed as a trench capacitor in a semiconductor substrate, in which the first electrode plate is formed as a doped section of the semiconductor substrate in a trench wall." As a result, this claim now includes all of the limitations of claim 14, which has been allowed. It is therefore respectfully submitted that claim 20 is allowable as well.

In view of the above, Applicants respectfully submit that this response complies with 37 C.F.R. § 1.116. Applicants further submit that the claims are in condition for allowance. No new matter has been added by this amendment. If the Examiner should have any questions, please contact Applicants' attorney at the number listed below. No fee is believed due in connection with this filing. However, in the event that there are any fees due, please charge the same, or credit any overpayment, to Deposit Account No. 50-1065.

Respectfully submitted,



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September 13, 2006
Date

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